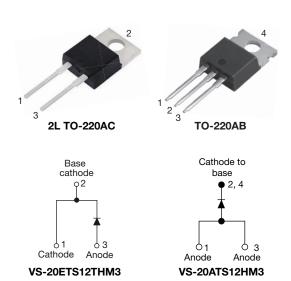
# **VS-20ETS12THM3, VS-20ATS12HM3**

Vishay Semiconductors

# High Voltage, Input Rectifier Diode, 20 A



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	20 A					
$V_{R}$	1200 V					
V <sub>F</sub> at I <sub>F</sub>	1.1 V					
I <sub>FSM</sub>	300 A					
T <sub>J</sub> max.	150 °C					
Package	2L TO-220AC, 3L TO-220AB					
Circuit configuration	Single					

#### **FEATURES**

- · Glass passivated pellet chip junction
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification



- High surge, low V<sub>F</sub> rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **APPLICATIONS**

- On-board and off-board EV/HEV battery chargers
- · Input rectification

### **DESCRIPTION**

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS					
Capacitive input filter T <sub>A</sub> = 55 °C, T <sub>J</sub> = 125 °C common heatsink of 1 °C/W	16.3	21	А					

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	VALUES	UNITS					
I <sub>F(AV)</sub>	Sinusoidal waveform	20	Α				
V <sub>RRM</sub>		1200	V				
I <sub>FSM</sub>		300	Α				
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.0	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS								
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA					
VS-20ETS12THM3, VS-20ATS12HM3	1200	1300	1					

# **VS-20ETS12THM3, VS-20ATS12HM3**

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 105 °C, 180° conduction half sine wave	20					
Maximum peak one cycle	1	10 ms sine pulse, rated V <sub>RRM</sub> applied	250	Α				
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300					
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	316	A <sup>2</sup> s				
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-5				
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s				

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
Maximum forward voltage drop	$V_{FM}$	20 A, T <sub>J</sub> = 25 °C	1.1	V			
Forward slope resistance	r <sub>t</sub>	T _ 150 °C	10.4	mΩ			
Threshold voltage	V <sub>F(TO)</sub>	1 J = 150 C	T <sub>J</sub> = 150 °C				
Maximum variana laakana ariiwant		T <sub>J</sub> = 25 °C	V Dated V	0.1	m A		
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	1.0	mA mA		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum thermal resistance, junction to case		$R_{thJC}$	DC operation	1.3	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.5				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style 2L TO-220AC	20ETS	S12TH			
			Case style 3L TO-220AB	20ATS12F				

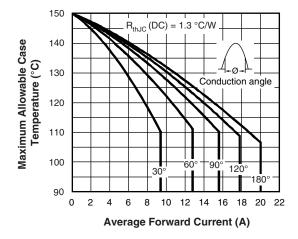


Fig. 1 - Current Rating Characteristics

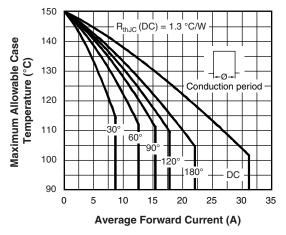


Fig. 2 - Current Rating Characteristics



### www.vishay.com

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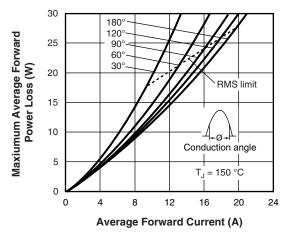


Fig. 3 - Forward Power Loss Characteristics

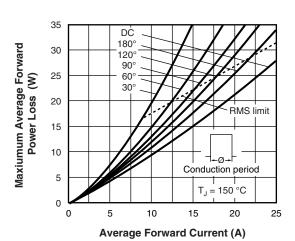


Fig. 4 - Forward Power Loss Characteristics

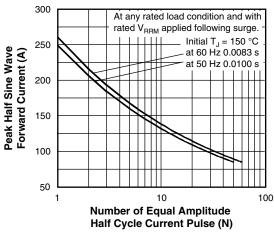


Fig. 5 - Maximum Non-Repetitive Surge Current

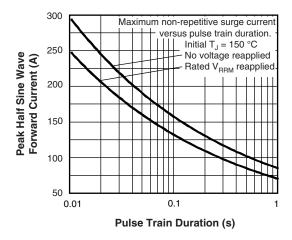


Fig. 6 - Maximum Non-Repetitive Surge Current

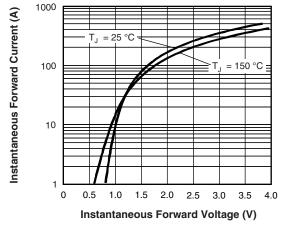


Fig. 7 - Forward Voltage Drop Characteristics

# **VS-20ETS12THM3, VS-20ATS12HM3**

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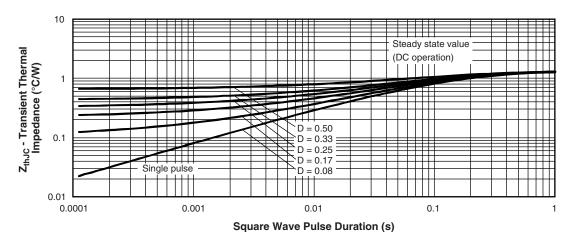


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

Device code	VS-	20	E	т	s	12	т	Н	М3
	1	2	3	4	5	6	7	8	9
	1 -	Vish	nay Sem	nicondu	ctors pro	oduct			
	2 -	Cur	rent rati	ing (20 =	= 20 A)				
	3 -	Circ	cuit con	figuratio	n:				
		E =	2L TO-	220AC					
		A =	3L TO-	220AB					
	4 -	Pac	kage:						
		T =	TO-220	)					
	5 -	Тур	e of silic	con:					
		S =	standar	rd recov	ery recti	fier			
	6 -	Volt	Voltage code x 100 = V <sub>RRM</sub> — 12 = 1200 V						
	7 -	• N	one = T	O-220A	В				_
		• T	= True	pin TO-2	220				
	8 -	H =	AEC-Q	101 qua	lified				
	9 -	Env	ironmen	ıtal digit:					

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-20ETS12THM3	50	1000	Antistatic plastic tubes					
VS-20ATS12HM3	50	1000	Antistatic plastic tubes					

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

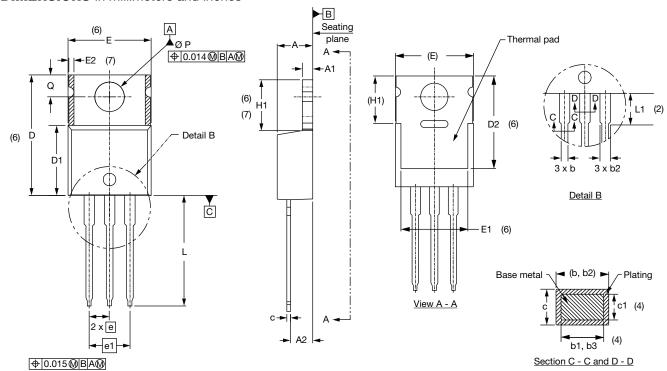
LINKS TO RELATED DOCUMENTS						
Dimensions	2L TO-220AC	www.vishay.com/doc?96069				
Dimensions	3L TO-220AB	www.vishay.com/doc?95222				
Part marking information	2L TO-220AC	www.vishay.com/doc?95391				
Part marking information	3L TO-220AB	www.vishay.com/doc?95028				
SPICE model		www.vishay.com/doc?97266				

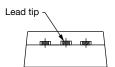


## Vishay Semiconductors

### **TO-220AB**

### **DIMENSIONS** in millimeters and inches





### Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES	HES NOTES	SYMBOL		IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183		D2	11.68	12.88	0.460	0.507	6	
A1	1.14	1.40	0.045	0.055		Е	10.11	10.51	0.398	0.414	3, 6	
A2	2.56	2.92	0.101	0.115		E1	6.86	8.89	0.270	0.350	6	
b	0.69	1.01	0.027	0.040		E2	ı	0.76	-	0.030	7	
b1	0.38	0.97	0.015	0.038	4	е	2.41	2.67	0.095	0.105		
b2	1.20	1.73	0.047	0.068		e1	4.88	5.28	0.192	0.208		
b3	1.14	1.73	0.045	0.068	4	H1	5.84	6.86	0.230	0.270	6, 7	
С	0.36	0.61	0.014	0.024		L	13.52	14.02	0.532	0.552		
c1	0.36	0.56	0.014	0.022	4	L1	3.32	3.82	0.131	0.150	2	
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147		
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118		

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

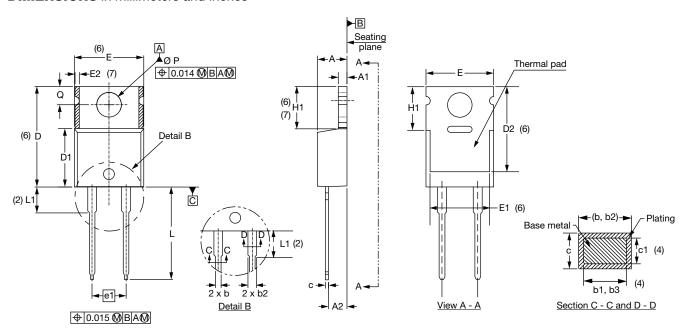
Revision: 23-Feb-2024 1 Document Number: 95222



## Vishay Semiconductors

### **TO-220AC 2L**

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES			
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.25	4.65	0.167	0.183			
A1	1.14	1.40	0.045	0.055			
A2	2.56	2.92	0.101	0.115			
b	0.69	1.01	0.027	0.040			
b1	0.38	0.97	0.015	0.038	4		
b2	1.20	1.73	0.047	0.068			
b3	1.14	1.73	0.045	0.068	4		
С	0.36	0.61	0.014	0.024			
c1	0.36	0.56	0.014	0.022	4		
D	14.85	15.25	0.585	0.600	3		
D1	8.38	9.02	0.330	0.355			
D2	11.68	12.88	0.460	0.507	6		
Е	10.11	10.51	0.398	0.414	3, 6		

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	

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- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$  Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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